

isc Silicon NPN Power Transistors

KSD1406

DESCRIPTION

- Collector-Emitter Sustaining Voltage-: V_{CEO(SUS)}= 60V(Min)
- Collector Current-I_C= 3A(Max.)
- Low Collector Saturation Voltage
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

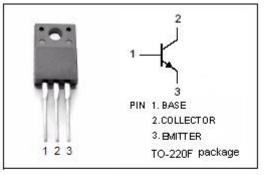
· Low frequency power amplifier

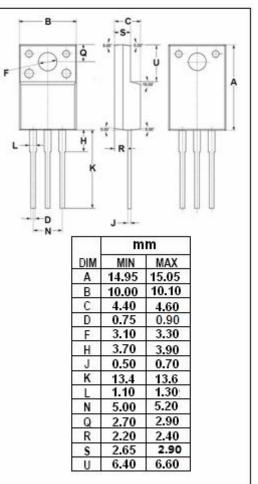
ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| SYMBOL | PARAMETER | VALUE | UNIT |
|------------------|--|---------|------|
| V _{CBO} | Collector-Base Voltage | 60 | v |
| V _{CEO} | Collector-Emitter Voltage | 60 | V |
| V _{EBO} | Emitter-Base Voltage | 7 | V |
| Ic | Collector Current-Continuous | 3 | А |
| IB | Base Current-Continuous | 0.5 | А |
| PT | Total Power Dissipation (@ $T_c=25^{\circ}C$ | 25 | W |
| TJ | Junction Temperature | 150 | °C |
| T _{stg} | Storage Temperature Range | -55~150 | °C |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | МАХ | UNIT |
|---------|--------------------------------------|-----|------|
| Rth j-c | Thermal Resistance, Junction to Case | 5 | °C/W |





1



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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP. | МАХ | UNIT |
|----------------------|--------------------------------------|---|-----|------|-----|------|
| Vceo(sus) | Collector-Emitter Sustaining Voltage | I _C = 50mA; I _B = 0 | 60 | | | V |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | I _C = 3A; I _B = 0.3A | | | 1.0 | V |
| V _{BE(On)} | Base-Emitter On Voltage | I _C = 0.5A; V _{CE} = 5V | | | 1.0 | V |
| Ісво | Collector Cutoff Current | At rated Voltage | | | 10 | μA |
| I _{CEO} | Collector Cutoff Current | At rated Voltage | | | 10 | μA |
| I _{EBO} | Emitter Cutoff Current | At rated Voltage | | | 10 | μA |
| h _{FE-1} | DC Current Gain | I _C = 0.5A; V _{CE} = 5V | 60 | | 320 | |
| h _{FE-2} | DC Current Gain | I _C = 3A; V _{CE} = 5V | 20 | | | |
| f⊤ | Current-Gain—Bandwidth Product | Ic= 0.5A; Vce= 5V | | 3 | | MHz |

h_{FE-1} Classifications

| Ο | Y | G |
|--------|---------|---------|
| 60-120 | 100-200 | 150-300 |

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2